

PRODUCTION DATA SHEET

DESCRIPTION

The LX1704 family represents a Microsemi. This CMOS stereo Class-D amplifier series is optimized for low applications where low power consumption external components. is desirable such as: portable speakers, systems.

The LX1704 family provides very new generation of a fully integrated low quiescent current consumption audio stereo Class-D amplifier from through the use of a proprietary output modulation scheme. This technology enables filterless operation in many voltage, low power operation and applications. The part features on board, minimum system cost. The products low Rdson, complementary output are ideal for use in battery powered MOSFET's that reduces the need for

The LX1704 is offered in a small DVDs, PMP, and other low power footprint, low profile, 4mm x 4mm 16pin MLPQ.

IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com

PRODUCT HIGHLIGHT Speaker Out 1 1 PVDD PVDD OUT1-PVSS1 OUT2 VDD [] // PVDD VDD PVDD2 -X1704 IN1+ OUT2+ Speaker Out 2 PVSS2 1 ENABLE

KEY FEATURES

- No Output Filter Required
- Low EMI Design
- Low Quiescent Current: 4mA
- Low Shutdown Current: 1µA
- Wide Supply Voltage Range: 2.5 - 5.5 Volt
- 2W Output Power into 4Ω Load with THD<1% @ 5.0V
- THD+N as Low as 0.1%
- Small Form Factor...16 pin MLP Package Only 4 x 4mm
- Built-in Clock Frequency
- Built-in Feedback Loop, Keep High Audio Fidelity
- Fixed 20dB Gain
- Full 20 20kHz Audio Bandwidth
- Shut-down Function
- Internal Thermal Shutdown
- High Efficiency: over 85% through Modulation Scheme and Class-D Operation
- Built-in De-Pop Circuit

APPLICATIONS

- Portable Speakers
- Portable DVD
- PMP / PMC
- Notebook PC

PACKAGE ORDER INFO				
T _A (°C)	Plastic MLPQ 4mm x 4mm 16-Pin RoHS Compliant / Pb-free			
0 to 70	LX1704CLQ			

Note: Available in Tape & Reel. Append the letters "TR" to the part number. (i.e. LX1704CLQ-TR)



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ABSOLUTE MAXIMUM RATINGS

Positive Supply Voltage (VDD, PVDD)	-0.3 to 6.5V
Analog Input Voltage (IN1+, IN1-, IN2+, IN2-)	
Digital Input Voltage(EN, MUTE)	0.3 to VDD + 0.3V
Operating Temperature Range (T _A)	0°C to +70°C
Maximum Operating Junction Temperature (T _J)	150°C
Storage Temperature Range	65°C to 150°C
Package Peak Temp. for Solder Reflow (40 seconds maximum expo	osure) 260°C (+0 -5)

Note: Exceeding these ratings could cause damage to the device. All voltages are with respect to Ground. Currents are positive into, negative out of specified terminal.

THERMAL DATA

LQ Plastic MLPQ 16-Pin 4mm x 4mm

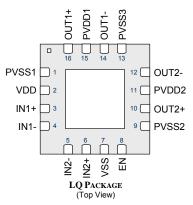
THERMAL RESISTANCE-JUNCTION TO AMBIENT, θ_{JA}

24.6°C/W

Junction Temperature Calculation: $T_J = T_A + (P_D \times \theta_{JA})$.

The θ_{JA} numbers are guidelines for the thermal performance of the device/pc-board system. All of the above assume no ambient airflow.

PACKAGE PIN OUT



RoHS / Pb-free 100% matte Tin Lead Finish

FUNCTIONAL PIN DESCRIPTION						
Name	Description					
VSS	Negative Supply to Analog Stage (ground)					
IN1-	Negative Audio Input Channel 1					
IN1+	Positive Audio Input Channel 1					
EN	Enable Pin, Active High					
IN2-	Negative Audio Input Channel 2					
IN2+	Positive Audio Input Channel 2					
VDD	Analog Positive Power Supply					
PVSS1 PVSS2 PVSS3	Negative Supply to Negative Output Stage (ground) for Channel1					
OUT1+	Positive Audio (PWM) Output for Channel 1					
PVDD1 & PVDD2	Positive supply to Positive Output Stage for Channel 1					
OUT1-	Negative Audio (PWM) Output for Channel 1					
OUT2+	Positive Audio (PWM) Output Channel 2					
OUT2-	Negative Audio (PWM) Output Channel 2					



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SYSTEM CHARACTERISTICS

The following specifications apply over the operating ambient temperature $0 \le T_A \le 70^{\circ}\text{C}$ except where otherwise noted and the following test conditions: PVDD = VDD = 5.0V, PVSS = VSS = 0V, RL = 4Ω

Parameter	Symbol	Tost Co	nditions		LX1704		Units
Farameter	Syllibol	Test Conditions		Min	Тур	Max	Ullits
Supply Current: Quiescent	I_{QQ}	No Load			2.5	5	mA
Supply Current: Shutdown Mode	I _{QQSD}	Disable Pin Active				1	μΑ
	Pa	THD+N = 1%		2.4			
Output Dawar & 4 Ohma		= 1kHz	THD+N = 10%		3.3		W
Output Power @ 4 Ohms		VDD = PVDD = 3.3V, Fin = 1kHz	THD+N = 1%		0.9		
			THD+N = 10%		1.2		
Power Efficiency	Н	VDD = PVDD = 5V, Fin = 1kHz			85		%
Total Harmonic Distortion @ 50% of Maxim Power	THD_N	VDD = PVDD = 5V, Fin = 1kHz, $R_L = 4\Omega$			0.1		%
Signal To Noise Ratio	SNR	VDD = PVDD = 5V, F = 1kHz, P _O = 1W, A-weighted			90		dB
Output Noise Floor	V _N	Input Grounded A-weighted 20 to 20kHz			100		μV_{RMS}
Frequency Response Lower Corner Frequency	F _{LO}	3dB relative to 1kHz		20		20K	Hz
Frequency Response		VDD = PVDD = 2.5 to 5.5V, RL = 4Ω, P _O = 200mW @ 20 to 80kHz, Filter less				3	dB
Power Supply Rejection Ratio	PSRR	Input Reffered, VDD = PVDD = 2.5V to 5.5V		55	60		dB
Common Mode Rejection Ratio	CMRR	VDD = PVDD = 2.5V to 5.5V		55	60		dB
Gain	G _{SYS}				20		dB



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ELECTRICAL CHARACTERISTICS

The following specifications apply over the operating ambient temperature $0 \le T_A \le 70^{\circ}\text{C}$ except where otherwise noted and the following test conditions: PVDD = VDD = 5.0V, PVSS = VSS = 0V, RL = 4Ω

Parameter	Symbol	Symbol Test Conditions		LX1704			Units
Parameter	Syllibol			Min	Тур	Max	Units
Supply Voltage	VDD PVDD			2.5		5.5	V
Oscillator Frequency	f _{SW}	VDD = PVDD = 2.5 to 5	5.5V		200		kHz
Supply Current: Quiescent		No Load	VDD = PVDD = 5V		2.5	5	mA
Supply Current: Quiescent	I _{QQ}		VDD = PVDD = 3.3V		2	4	
Supply Current: Shutdown Mode	I _{QQSD}	Disable Pin Active				1	μΑ
Power Supply Rejection Ratio	PSRR	VDD = PVDD = 2.5V to 5.5V		55	60		dB
Input Resistance	R _{IN}	VDD = PVDD = 2.5V to 5.5V Single Ended			18		ΚΩ
Output DC Offset	V_{OFF}	Input Shorted to GND		-50		+50	mV
		VDD = PVDD = 5V	P Channel		350		mΩ
			N Channel		350		
Static Drain-to-Source ON-	RDSON	VDD = PVDD = 3.3V	P Channel		470		
Resistance			N Channel		470		
		\(\(\mathbb{D}\)	P Channel			600	
		VDD = PVDD = 2.5V	N Channel			600	
Stage Gain	G _H	VDD = PVDD = 2.5V to 5.5V		9	10	11	V/V
Thermal Indicator Junction	TJ				150		°C
Under Voltage Threshold Level	V_{DD}			1.8	2.0	2.2	V
Enable Threshold	EN			2.10	2.25	2.40	V



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SIMPLIFIED BLOCK DIAGRAM LX1704 Triangle Wave PVDD2 Generator PVDD1 DRIVER VINP [OUTP Dynamic Pulse Generation VINN 🗀 OUTN DRIVER PVSS1 LP De-pop signal PVSS2 VDD 🗀 ground Generation LP ☐ EN VSS 📋

Figure 1 – LX1704 Simplified Block Diagram (Half Circuit)



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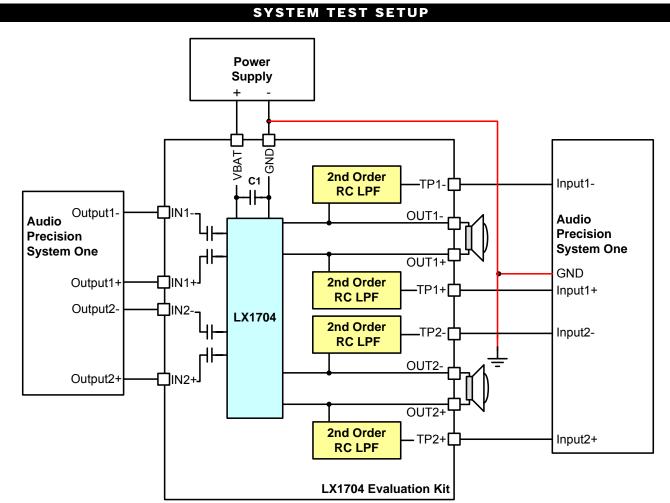


Figure 2 - Typical Evaluation Test Setup Circuit

Default Settings:

Equipments: Audio Precision SYSTEM 1

Oscilloscope,

Power Supply ~ +5V; Supply Voltage: 2.5V / 3.3V / 5.0V 3 corner voltages On-Board passive LPF: 40kHz cut off frequency (-6dB)

AP settings: 10Hz ~ 22KHz BPF



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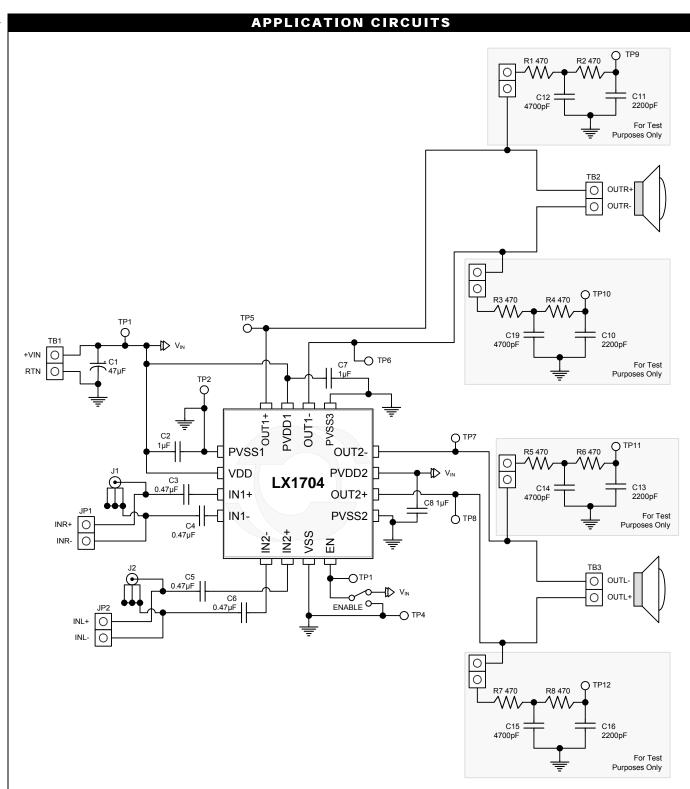


Figure 3 – Typical LX1704 Application



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FUNCTIONAL DESCRIPTION

GENERAL DESCRIPTION

The LX1704 is a filterless, low-EMI, class-D audio power amplifier. It offers high performance (THD+N is just 0.1% @ 2W), high efficiency (>85% @ 1.2W), and best in class EMI radiation (just 20dB μ V/m). The internal signal path is completely differential to minimize common-mode noise pickup. The inputs may be driven single-ended or differentially and they may be direct or AC coupled. The LX1704 may be operated with just a single decoupling capacitor.

FILTERLESS 3-LEVEL CLASS-D MODULATION

The LX1704 output stage is configured as a full H-bridge push-pull driver. The speaker must be driven differentially from the OUTP and OUTN pins. Each side of the speaker is driven by a 200KHz switching signal that transitions between V_{DD} and GND. With zero input voltage, the duty cycle at each output is around 50% and the signals are inphase with each other. In this case, there is basically no differential voltage across the speaker. When the input signal goes positive, the duty cycle at OUTP increases above 50% and the duty cycle at OUTN decreases below 50%. This causes a net positive current to flow into the speaker. A negative input voltage causes the OUTN duty cycle to increase and the OUTP duty cycle to decrease which causes a net negative current to flow into the speaker. The differential voltage across the speaker has a fundamental frequency of twice the 200KHz switching frequency. The speaker itself serves as the low pass filter which then recreates the audio signal. This type of modulation can be described as driving $+V_{DD}$, $-V_{DD}$, and 0Vacross the speaker which is why it is referred to as 3-Level modulation.

Classical, 2-Level modulation drives either $+V_{DD}$ or $-V_{DD}$ across the speaker at all times. This scheme requires an L-C filter between the amplifier's outputs and the speaker in order to keep the output current low.

LOW-EMI OUTPUT STAGE WITH SLEW RATE LIMITING AND ACTIVE OVERSHOOT CLAMPING

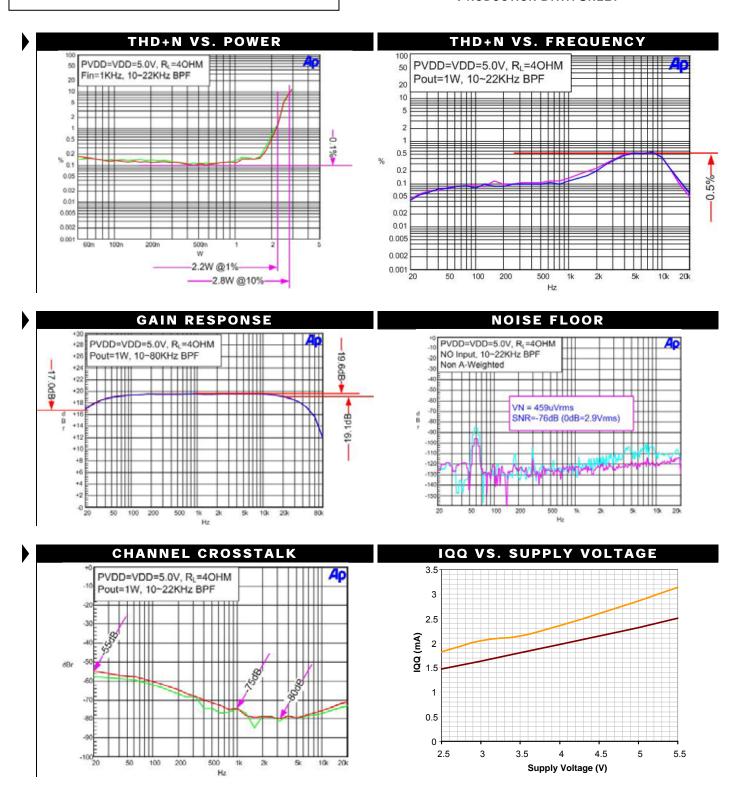
With 3-Level modulation, the carrier frequency drives a full amplitude common-mode signal to the speaker wires. This can cause high EMI radiation. One way to combat this would be to filter the outputs with LC filters or ferrite beads located close to the amplifier. In the LX1704, the output stage has been carefully designed to minimize EMI radiation so that these types of filters are not required. Slew rate limiting is used to keep the outputs from switching too quickly. Active overshoot clamping is used to minimize the inductive overshoot which occurs at each transition. These two techniques allow the LX1704 to easily meet FCC standards for radiated emissions when driving up to 3 meters of speaker wire.

DIFFERENTIAL SIGNAL PATH, WIDE DYNAMIC RANGE, AND BUILT-IN THERMAL OVERLOAD PROTECTION

The fully differential signal path uses Pulse Width Modulation and multiple feedback loops to provide high performance and low distortion. This is all fully-integrated to eliminate the need for any external feedback components or filters. The gain is fixed by internal resistors at 20dB. The differential signal path and internal voltage boosters allow for wide dynamic range. In fact, the LX1704 can be operated from supplies as low as 2.5V and as high as 5.5V. The output power will be limited by the available supply voltage. An internal thermal sensing circuit shuts down the outputs when the junction temperature exceeds about 150°C to provide thermal overload protection.

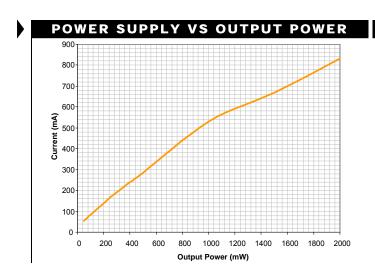


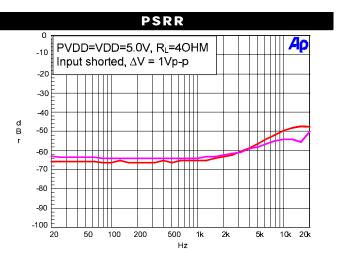
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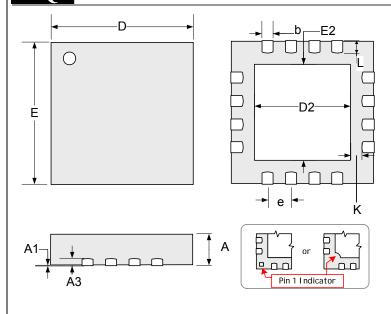
POWER VS SUPPLY VOLTAGE 3500 3000 2500 Power/CH (mW) 2000 1500 1000 500 0 3.5 4.5 5 5.5 2.5 Supply Voltage (V)



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PACKAGE DIMENSIONS

16-Pin MLPQ Plastic (4mm x 4mm EP / 114x114Cu Exposed Pad)



	MILLIMETERS		INCHES		
Dim	MIN	MAX	MIN	MAX	
Α	0.80	1.00	0.031	0.039	
A1	0	0.05	0	0.002	
A3	0.18	0.30	0.007	0.012	
b	0.23	0.38	0.009	0.015	
D	4.00 BSC		0.157 BSC		
E	4.00 BSC		0.157 BSC		
е	0.65 BSC		0.026 BSC		
D2	2.55	2.80	0.100	0.110	
E2	2.55	2.80	0.100	0.110	
K	0.20	-	0.008	-	
L	0.30	0.50	0.012	0.020	

Note:

 Dimensions do not include mold flash or protrusions; these shall not exceed 0.155mm(.006") on any side. Lead dimension shall not include solder coverage.



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NOTES

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